

	Type	L #	Hits	Search Text	DBs
1	BRS	L4	1827	349/43	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
2	BRS	L5	60122	<b>amorphous ADJ silicon</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
3	BRS	L6	32469	<b>ohmic ADJ contact</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>

	Type	L #	Hits	Search Text	DBs
4	BRS	L7	566	<b>4 and 4 and 6</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
5	BRS	L8	499	<b>4 and 5 and 6</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
6	BRS	L9	2437	<b>5 same 6</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>

	Type	L #	Hits	Search Text	DBs
7	BRS	L10	381	4 and 9	<b>US-</b> <b>PGPUB</b> ; <b>USPAT;</b> <b>EPO;</b> <b>JPO;</b> <b>DERWE</b> <b>NT;</b> <b>IBM_TD</b> <b>B</b>
8	BRS	L11	32434	storage ADJ capacitor	<b>US-</b> <b>PGPUB</b> ; <b>USPAT;</b> <b>EPO;</b> <b>JPO;</b> <b>DERWE</b> <b>NT;</b> <b>IBM_TD</b> <b>B</b>
9	BRS	L12	1542	349/106	<b>US-</b> <b>PGPUB</b> ; <b>USPAT;</b> <b>EPO;</b> <b>JPO;</b> <b>DERWE</b> <b>NT;</b> <b>IBM_TD</b> <b>B</b>

	Type	L #	Hits	Search Text	DBs
10	BRS	L13	145	<b>L12 and 11</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
11	BRS	L14	139	<b>13 and color</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>
12	IS&R	L16	2	<b>("6307602").PN.</b>	<b>US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B</b>

	Type	L #	Hits	Search Text	DBs
13	BRS	L17	13171	color same (gate scan\$4) ADJ line	US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B
14	BRS	L18	299	12 and 17	US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B
15	IS&R	L19	4	(("20010005245") or ("4470667")).PN.	US- PGPUB ; USPAT; EPO; JPO; DERWE NT; IBM_TD B

	Type	L #	Hits	Search Text	DBs
16	BRS	L20	2	Jp ADJ "62250416"	<b>US-</b> <b>PGPUB</b> ; <b>USPAT;</b> <b>EPO;</b> <b>JPO;</b> <b>DERWE</b> <b>NT;</b> <b>IBM_TD</b> <b>B</b>